

# High-voltage Switching Transistor (Power Supply) (120V, 7A)

## 2SC5575

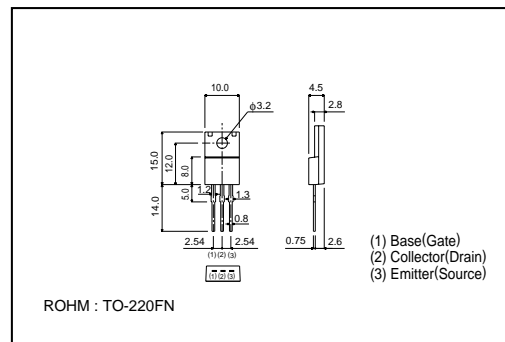
### ●Features

- 1) Low  $V_{CE(sat)}$ . (Typ. 0.17V at  $I_C / I_B = 5 / 0.5A$ )
- 2) Fast switching. ( $t_f$ : Typ. 0.18 $\mu s$  at  $I_C = 5A$ )
- 3) Wide SOA. (safe operating area)

### ●Absolute maximum ratings ( $T_a = 25^\circ C$ )

| Parameter                   | Symbol    | Limits      | Unit                  |
|-----------------------------|-----------|-------------|-----------------------|
| Collector-base voltage      | $V_{CBO}$ | 250         | V                     |
| Collector-emitter voltage   | $V_{CEO}$ | 120         | V                     |
| Emitter-base voltage        | $V_{EBO}$ | 12          | V                     |
| Collector current           | $I_C$     | 7           | A                     |
|                             |           | 15          | A( $t=100ms$ )        |
| Collector power dissipation | $P_C$     | 2           | W                     |
|                             |           | 25          | W( $T_C=25^\circ C$ ) |
| Junction temperature        | $T_j$     | 150         | $^\circ C$            |
| Storage temperature         | $T_{stg}$ | -55 -- +150 | $^\circ C$            |

### ●External dimensions (Units : mm)



### ●Packaging specifications and $h_{FE}$

|                              |          |
|------------------------------|----------|
| Type                         | 2SC5575  |
| Package                      | TO-220FN |
| $h_{FE}$                     | E        |
| Code                         | -        |
| Basic ordering unit (pieces) | 500      |

### ●Electrical characteristics ( $T_a = 25^\circ C$ )

| Parameter                            | Symbol         | Min. | Typ. | Max. | Unit    | Conditions   |
|--------------------------------------|----------------|------|------|------|---------|--|
| Collector-emitter breakdown voltage  | $V_{CEX(SUS)}$ | 125  | —    | —    | V       | $I_{CP}=8A, I_{B1}=-I_{B2}=0.5A, I_C=5A, L=200\mu H$ clamped |
| Collector cutoff current             | $I_{CBO}$      | —    | —    | 10   | $\mu A$ | $V_{CB}=100V$  |
| Collector cutoff current             | $I_{EBO}$      | —    | —    | 10   | $\mu A$ | $V_{EB}=12V$   |
| Collector-emitter saturation voltage | $V_{CE(sat)}$  | —    | —    | 0.6  | V       | $I_C/I_B=5A/0.5A$  |
| Base-emitter saturation voltage      | $V_{BE(sat)}$  | —    | —    | 1.2  | V       | $I_C/I_B=5A/0.5A$  |
| DC current transfer ratio            | $h_{FE}$       | 100  | —    | 200  | —       | $V_{CE}/I_C=5V/3A$   |
| Transition frequency                 | $f_T$          | —    | 20   | —    | MHz     | $V_{CE}=10V, I_E=-0.5A$                                      |
| Output capacitance                   | $C_{ob}$       | —    | 150  | —    | pF      | $V_{CB}=10V, I_E=0A, f=1MHz$                                 |
| Turn-on time                         | $t_{on}$       | —    | —    | 0.5  | $\mu s$ | $I_C=5A, R_L=10\Omega$                                       |
| Storage time                         | $t_{stg}$      | —    | —    | 2.5  | $\mu s$ | $I_{B1}=-I_{B2}=0.5A$  |
| Fall time                            | $t_f$          | —    | —    | 0.5  | $\mu s$ | $V_{CC}=50V$   |
| Collector cutoff current             | $I_{CEO}$      | —    | —    | 2    | mA      | $V_{CE}=100V, T_a=125^\circ C$                               |